# uClamp3311P Low Voltage µClamp™ for ESD and CDE Protection

### PROTECTION PRODUCTS - MicroClamp™

### Description

The µClamp™ series of Transient Voltage Suppressors (TVS) are designed to replace multilayer varistors (MLVs) in portable applications where low operating voltage is vital. They offer superior electrical characteristics such as lower clamping voltage and no device degradation when compared to MLVs. They are designed to protect sensitive semiconductor components from damage or upset due to electrostatic discharge (ESD), lightning, electrical fast transients (EFT), and cable discharge events (CDE).

The  $\mu Clamp^{TM}3311P$  is constructed using Semtech's proprietary EPD process technology. The EPD process provides low standoff voltages with significant reductions in leakage currents and capacitance over siliconavalanche diode processes. They feature a true operating voltage of 3.3 volts for superior protection when compared to traditional pn junction devices.

The μClamp<sup>TM</sup>3311P is in an 2-pin, RoHS/WEEE compliant, SLP1006P2 package. It measures 1.0 x 0.6 x 0.5mm. The leads are spaced at a pitch of 0.65mm and are finished with lead-free NiPdAu. Each device will protect one line operating at 3.3 volts. It gives the designer the flexibility to protect single lines in applications where arrays are not practical. They may be used to meet the ESD immunity requirements of IEC 61000-4-2, Level 4 (±15kV air, ±8kV contact discharge). The combination of small size and high ESD surge capability makes them ideal for use in portable applications such as cellular phones, digital cameras, and MP3 players.

#### **Features**

- ◆ Transient protection for data lines to IEC 61000-4-2 (ESD) ±15kV (air), ±8kV (contact) IEC 61000-4-4 (EFT) 40A (tp = 5/50ns) Cable Discharge Event (CDE)
- Ultra-small package (1.0 x 0.6 x 0.5mm)
- Protects one data line
- Low clamping voltage
- Working voltage: 3.3V
- Low leakage current
- Solid-state silicon-avalanche technology

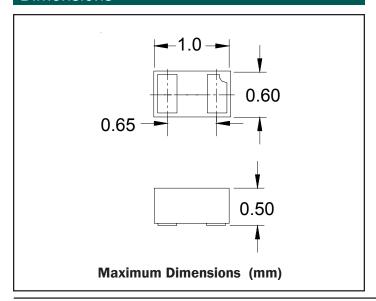
### Mechanical Characteristics

- ◆ SLP1006P2 package
- ◆ RoHS/WEEE Compliant
- Nominal Dimensions: 1.0 x 0.6 x 0.5 mm
- Lead Finish: NiPdAu
- Molding compound flammability rating: UL 94V-0
- Marking: Marking code, cathode band
- Packaging : Tape and Reel

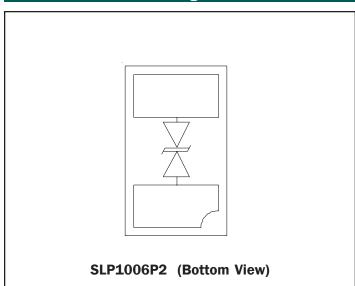
### **Applications**

- Cellular Handsets & Accessories
- Notebooks & Handhelds
- Portable Instrumentation
- Digital Cameras
- Peripherals
- MP3 Players

#### **Dimensions**



### Schematic & PIN Configuration





# Absolute Maximum Rating

Rating	Symbol	Value	Units
Peak Pulse Power (tp = 8/20μs)	$P_{pk}$	90	Watts
Maximum Peak Pulse Current (tp = 8/20μs)	I <sub>pp</sub>	5	Amps
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	V <sub>PP</sub>	+/- 25 +/- 20	kV
Operating Temperature	T,	-40 to +85	°C
Storage Temperature	T <sub>STG</sub>	-55 to +150	°C

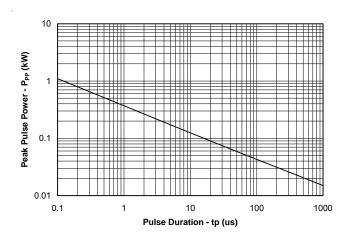
# Electrical Characteristics (T=25°C)

Parameter	Symbol	Conditions	Minimum	Typical	Maximum	Units
Reverse Stand-Off Voltage	V <sub>RWM</sub>				3.3	V
Punch-Through Voltage	V <sub>PT</sub>	I <sub>PT</sub> = 2μA	3.5			V
Snap-Back Voltage	V <sub>SB</sub>	I <sub>SB</sub> = 50mA	2.8			V
Reverse Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> = 3.3V		0.05	0.5	μΑ
Clamping Voltage	V <sub>c</sub>	$I_{pp} = 1A$ , tp = 8/20µs			8	V
Clamping Voltage	V <sub>c</sub>	$I_{pp} = 5A$ , tp = 8/20µs			18	V
Junction Capacitance	C <sub>j</sub>	I/O pin to Gnd V <sub>R</sub> = OV, f = 1MHz		12	15	pF
		I/O pin to Gnd $V_R = 3.3V, f = 1MHz$		10		pF

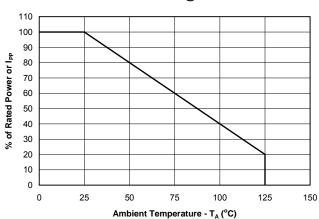


### **Typical Characteristics**

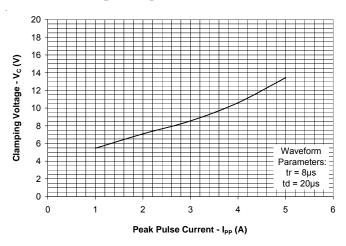
#### Non-Repetitive Peak Pulse Power vs. Pulse Time



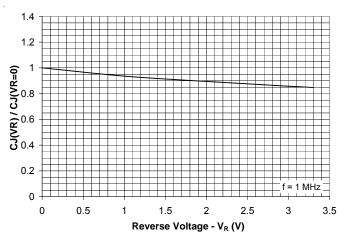
### **Power Derating Curve**



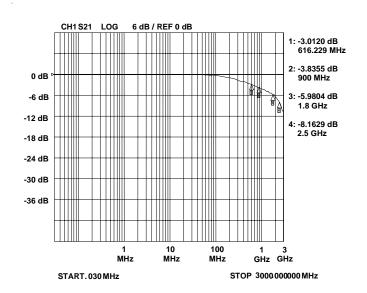
#### Clamping Voltage vs. Peak Pulse Current



### Junction Capacitance vs. Reverse Voltage



#### **Insertion Loss S21**





### **Applications Information**

#### **Device Connection Options**

The µClamp3311P is designed to protect one data line operating up to 3.3 volts. It will present a high impedance to the protected line up to 3.3 volts. It will "turn on" when the line voltage exceeds 3.5 volts. The device is bidirectional and may be used on lines where the signal polarity is above and below ground. These devices are not recommended for use on dc power supply lines due to their snap-back voltage characteristic.

#### **EPD TVS Characteristics**

These devices are constructed using Semtech's proprietary EPD technology. The structure of the EPD TVS is vastly different from the traditional pn-junction devices. At voltages below 5V, high leakage current and junction capacitance render conventional avalanche technology impractical for most applications. However, by utilizing the EPD technology, these devices can effectively operate at 3.3V while maintaining excellent electrical characteristics.

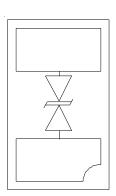
The EPD TVS employs a complex nppn structure in contrast to the pn structure normally found in traditional silicon-avalanche TVS diodes. The EPD mechanism is achieved by engineering the center region of the device such that the reverse biased junction does not avalanche, but will "punch-through" to a conducting state. This structure results in a device with superior DC electrical parameters at low voltages while maintaining the capability to absorb high transient currents.

# Circuit Board Layout Recommendations for Suppression of ESD.

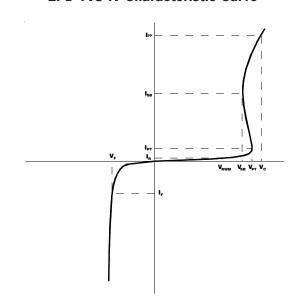
Good circuit board layout is critical for the suppression of ESD induced transients. The following guidelines are recommended:

- Place the TVS near the input terminals or connectors to restrict transient coupling.
- Minimize the path length between the TVS and the protected line.
- Minimize all conductive loops including power and ground loops.
- The ESD transient return path to ground should be kept as short as possible.
- Never run critical signals near board edges.
- Use ground planes whenever possible.

#### **Device Schematic & Pin Configuration**



#### **EPD TVS IV Characteristic Curve**





### Applications Information - Spice Model

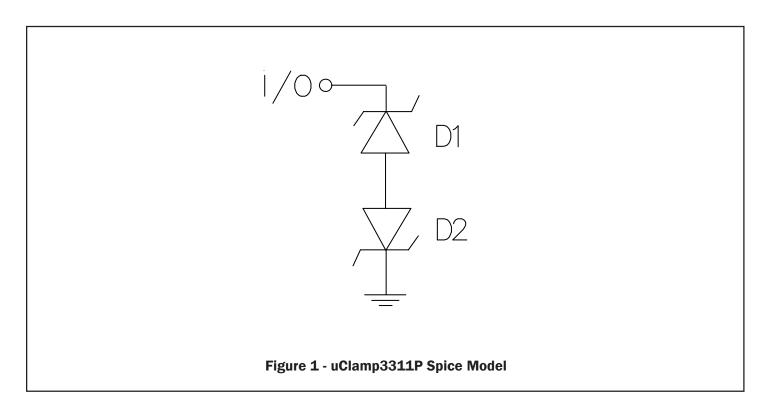
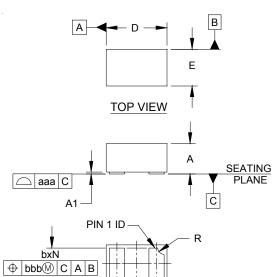


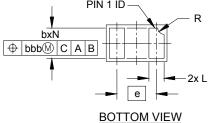
Table 1 - uClamp3311P Spice Parameters							
Parameter	Unit	D1 (TVS)	D2 (TVS)				
IS	Amp	1E-20	1E-20				
BV	Volt	3.8	3.8				
VJ	Volt	0.7	0.7				
RS	Ohm	1.1	1.1				
IBV	Amp	1E-3	1E-3				
C10	Farad	20E-12	20E-12				
TT	sec	2.541E-9	2.541E-9				
М		0.214	0.214				
N		1.1	1.1				
EG	eV	1.11	1.11				



### Outline Drawing - SLP1006P2



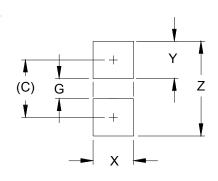
DIMENSIONS							
ПИ	11	<b>ICHE</b>	S	MILL	IMET	ERS	
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	.016	.020	.022	0.40	0.50	0.55	
A1	.000	.001	.002	0.00	0.03	0.05	
b	.018	.020	.022	0.45	0.50	0.55	
D	.035	.039	.043	0.90	1.00	1.10	
E	.020	.024	.028	0.50	0.60	0.70	
е	.0	26 BS	SC SC	0.65 BSC			
L	.008	.010	.012	0.20	0.25	0.30	
R	.002	.004	.006	0.05	0.10	0.15	
N		2		2			
aaa	.003 .004			0.08			
bbb				0.10			



#### NOTES:

1. CONTROLLING DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES).

### Land Pattern - SLP1006P2



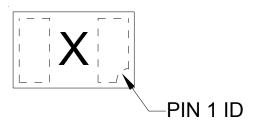
	DIMENSIONS							
DIM	INCHES	MILLIMETERS						
С	(.033)	(0.85)						
G	.012	0.30						
Χ	.024	0.60						
Y	.022	0.55						
Ζ	.055	1.40						

#### NOTES:

- 1. CONTROLLING DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES).
- 2. THIS LAND PATTERN IS FOR REFERENCE PURPOSES ONLY. CONSULT YOUR MANUFACTURING GROUP TO ENSURE YOUR COMPANY'S MANUFACTURING GUIDELINES ARE MET.



# Marking Code



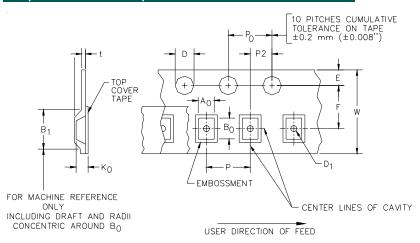
### **Ordering Information**

Part Number	Working Voltage	Qty per Reel	Reel Size
uClamp3311P.TCT	3.3V	3,000	7 Inch

#### Notes:

1) This is a lead-free, RoHS/WEEE compliant product MicroClamp, uClamp and  $\mu\text{Clamp}$  are marks of Semtech Corporation

### Tape and Reel Specification



AO	В0	ко
0.69 +/-0.10 mm	1.19 +/-0.10 mm	0.66 +/-0.10 mm

Tape Width		D	D1	E	F	Р	PO	P2	Т	w
8 mn	4.2 mm (.165)	1.5 + 0.1 mm - 0.0 mm (0.59 +.005 000)	0.4 mm ±0.25 (.031)	1.750±.10 mm (.069±.004)	3.5±0.05 mm (.138±.002)	4.0±0.10 mm (.157±.00- 4)	4.0±0.1 mm (.157±.00- 4)	2.0±0.05 mm (.079±.002)	0.254±0.02 mm (.016)	8.0 mm + 0.3 mm - 0.1 mm (.312±.012)

### **Contact Information**

Semtech Corporation Protection Products Division 200 Flynn Road, Camarillo, CA 93012 Phone: (805)498-2111 FAX (805)498-3804

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